Single and Dual Low Voltage, Rail-to-Rail Input and Output, Operational Amplifiers

The LMV931 Single and LMV932 Dual are CMOS low-voltage operational amplifiers which can operate on single-sided power supplies (1.8 V to 5.0 V) with rail-to-rail input and output swing. Both devices come in small state-of-the-art packages and require very low quiescent current making them ideal for battery-operated, portable applications such as notebook computers and hand-held instruments. Rail-to-Rail operation provides improved signal-to-noise performance plus the small packages allow for closer placement to signal sources thereby reducing noise pickup.

The single LMV931 is offered in space saving SC70-5 package. The dual LMV932 is in a Micro8. These small packages are very beneficial for crowded PCB's.

Features

- Performance Specified on Single-Sided Power Supply: 1.8 V, 2.7 V, and 5 V
- Small Packages:

LMV931 in a SC-70 LMV932 in a Micro8

- No Output Crossover Distortion
- Extended Industrial Temperature Range: -40°C to +125°C
- Low Quiescent Current 210 μA, Max Per Channel
- No Output Phase-Reversal from Overdriven Input
- These are Pb-Free Devices

Typical Applications

- Notebook Computers, Portable Battery-Operated Instruments, PDA's
- Active Filters, Low-Side Current Monitoring

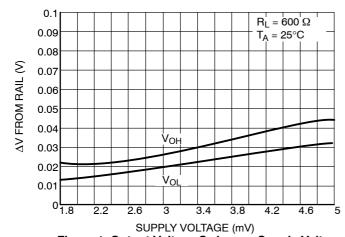


Figure 1. Output Voltage Swing vs. Supply Voltage



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MARKING DIAGRAMS

LMV931 (Single)



SC-70 CASE 419A





TSOP-5 CASE 483



M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

LMV932 (Dual)



Micro8[™] CASE 846A



A = Assembly Location

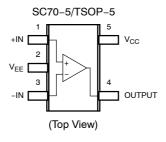
Y = Year
W = Work Week
Pb-Free Package

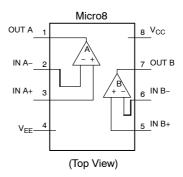
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 17 of this data sheet.

PIN CONNECTIONS





MAXIMUM RATINGS

Symbol	Rating	Value	Unit	
Vs	Supply Voltage (Operating Range V _S = 1.8 V to 5.5 V)	5.5	V	
V_{IDR}	Input Differential Voltage	± Supply Voltage	V	
V _{ICR}	Input Common Mode Voltage Range	-0.5 to (V+) + 0.5	V	
	Maximum Input Current	10	mA	
t _{So}	Output Short Circuit (Note 1)	Continuous		
TJ	Maximum Junction Temperature (Operating Range -40°C to	85°C)	150	°C
$\theta_{\sf JA}$	Thermal Resistance:	SC-70 TSOP-5 Micro8	280 333 238	°C/W
T _{stg}	Storage Temperature		-65 to 150	°C
	Mounting Temperature (Infrared or Convection ≤ 30 sec)	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ESD data available upon request.

 Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

1.8 V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 1.8 \text{ V}$, $V^- = 0 \text{ V}$, $V_{CM} = V + /2$, $V_O = V^+ / 2$ and $R_L > 1 \text{ M}\Omega$. Typical specifications represent the most likely parametric norm.

Parameter Symbo		Condition		Тур	Max	Unit	
Input Offset Voltage	V _{IO}	LMV931 (Single) (-40°C to +125°C)		1	6	mV	
		LMV932 (Dual) (-40°C to +125°C)		1	7.5		
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C	
Input Bias Current (Note 2)	Ι _Β	-40°C to +125°C		< 1		nA	
Input Offset Current (Note 2)	I _{IO}	−40°C to +125°C	-40°C to +125°C			nA	
Supply Current	I _{CC}	In Active Mode		75	185	μΑ	
(per Channel)		-40°C to +125°C			205		
Common Mode	CMRR	$0 \text{ V} \leq \text{V}_{\text{CM}} \leq 0.6 \text{ V}, 1.4 \text{ V} \leq \text{V}_{\text{CM}} \leq 1.8 \text{ V}$	50	70		dB	
Rejection Ratio		− 40°C to +125°C	50				
		$-0.2 \text{ V} \le \text{ V}_{\text{CM}} \le 0 \text{ V}, 1.8 \text{ V} \le \text{ V}_{\text{CM}} \le 2 \text{ V}$	50	70			
Power Supply	PSRR	$1.8 \text{ V} \le \text{V}^+ \le 5 \text{ V}, \text{V}_{\text{CM}} = 0.5 \text{ V}$	50	70		dB	
Rejection Ratio		-40°C to +125°C	50				
Input Common-Mode Voltage Range	Vсм	For CMRR ≥ 50 dB and T _A = 25°C	V ⁻ - 0.2	-0.2 to 2.1	V ⁺ + 0.2	V	
		For CMRR ≥ 50 dB and T _A = - 40°C to +85°C	V -		V ⁺]	
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V ⁻ + 0.2		V+ - 0.2		
Large Signal Voltage	A _V	R_L = 600 Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	77	101		dB	
Gain LMV931 (Single) (Note 2)		-40°C to +125°C					
		R_L = 2 k Ω to 0.9V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	to 0.9V, V _O = 0.2 V to 1.6 V, V _{CM} = 0.5 V 80 10				
		−40°C to +125°C	75				
Large Signal Voltage	1	R_L = 600 Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	75	90			
Gain LMV932 (Dual) (Note 2)		-40°C to +125°C	72				
		R_L = 2 k Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	78	100			
		-40°C to +125°C	75				
Output Swing	V _{OH}	R_L = 600 Ω to 0.9V, V_{IN} = \pm 100 mV	1.65	1.72		V	
		-40°C to +125°C	1.63				
	V _{OL}	R_L = 600 Ω to 0.9V, V_{IN} = \pm 100 mV		0.077	0.105		
		-40°C to +125°C			0.12		
	V _{OH}	R_L = 2 k Ω to 0.9V, V_{IN} = \pm 100 mV	1.75	1.77			
		-40°C to +125°C	1.74				
	V _{OL}	R_L = 2 k Ω to 0.9 V, V_{IN} = \pm 100 mV		0.24	0.035	1	
		-40°C to +125°C			0.04		
Output Short Circuit	I _O	Sourcing, Vo = 0 V, V _{IN} = +100 mV	4.0	30		mA	
Current		-40°C to +125°C	3.3				
		Sinking, Vo = 1.8V, V _{IN} = −100 mV	7.0	60			
		-40°C to +125°C	5.0				

^{2.} Guaranteed by design and/or characterization.

1.8V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_{+} = 1.8$ V, V-=0 V, $V_{CM}=2.0$ V, $V_$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 3)		0.35		V/μS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	Θm			67		0
Gain Margin	Gm			7		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 0.5 V		60		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.023		%
Amplifier-to-Amplifier Isolation		(Note 4)		123		dB

^{3.} Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.

4. Input referred, $R_L = 100 \text{ k}\Omega$ connected to V+/2. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V, $V_{O}^{\cdot} = V_{+}$).

2.7V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 2.7$ V, $V^- = 0$ V, $V_{CM} = V_{CM} = V$

Parameter Symbo		mbol Condition		Тур	Max	Unit	
Input Offset Voltage	V _{IO}	V _{IO} LMV931 (Single) (-40°C to +125°C)		1	6	mV	
Input Offset Voltage TOV		LMV932 (Dual) (-40°C to +125°C)		1	7.5		
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C	
Input Bias Current (Note 5)	I _B	-40°C to +125°C		< 1		nA	
Input Offset Current (Note 5)	I _{IO}	-40°C to +125°C < 1			nA		
Supply Current (per	Icc	In Active Mode		80	190	μΑ	
Channel)		-40°C to +125°C			210		
Common Mode	CMRR	0 V \leq V _{CM} \leq 1.5 V, 2.3 V \leq V _{CM} \leq 2.7 V	50	70		dB	
Rejection Ratio		−40°C to +125°C	50				
		$-0.2 \text{ V} \leq \text{V}_{\text{CM}} \leq 0 \text{ V}, 2.7 \text{ V} \leq \text{V}_{\text{CM}} \leq 2.9 \text{ V}$	50	70			
Power Supply	PSRR	$1.8~V~\leq~V^+~\leq~5~V,~V_{CM}=0.5~V$	50	70		dB	
Rejection Ratio		-40°C to +125°C	50				
Input Common-Mode Voltage Range	VcM	For CMRR \geq 50 dB and T _A = 25°C	V- - 0.2	-0.2 to 3.0	V+ + 0.2	V	
		For CMRR \geq 50 dB and T _A = -40°C to +85°C	V-		V ⁺	1	
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V- + 0.2		V+ - 0.2		
Large Signal Voltage	A_V $R_L = 600 Ω to 1.35 V, V_O = 0.2 V to 2.5 V$		87	104		dB	
Gain LMV931 (Single) (Note 5)		-40°C to +125°C 86					
, , ,		$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}, V_O = 0.2 \text{ V to } 2.5 \text{ V}$ 92 110					
		-40°C to +125°C	91				
Large Signal Voltage	A _V	R_L = 600 Ω to 1.35 V, V_O = 0.2 V to 2.5 V	78	90			
Gain LMV932 (Dual) (Note 5)		-40°C to +125°C	75			7	
,		R_L = 2 k Ω to 1.35 V, V_O = 0.2 V to 2.5 V	81	100			
		-40°C to +125°C	78				
Output Swing	V _{OH}	R_L = 600 Ω to 1.35 V, V_{IN} = \pm 100 mV	2.55	2.62		V	
		-40°C to +125°C	2.53				
	V _{OL}	R_L = 600 Ω to 1.35 V, V_{IN} = \pm 100 mV		0.083	0.11		
		-40°C to +125°C			0.13		
	V _{OH}	R_L = 2 k Ω to 1.35 V, V_{IN} = \pm 100 mV	2.65	2.675			
		-40°C to +125°C	2.64				
	V _{OL}	$R_L = 2 \text{ k}\Omega$ to 1.35 V, $V_{IN} = \pm 100 \text{ mV}$	1	0.025	0.04	7	
		-40°C to +125°C			0.045		
Output Short Circuit	I _O	Sourcing, Vo = 0 V, $V_{IN} = \pm 100 \text{ mV}$	20	65		mA	
Current		-40°C to +125°C	15				
		Sinking, Vo = 0 V, V _{IN} = -100 mV	18	75			
		-40°C to +125°C	12				

^{5.} Guaranteed by design and/or characterization.

2.7V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_{+} = 2.7$ V, $V-=0~V,~V_{CM}=2.0V~,\\ Vo=V+/2~\\ and~R_L>1~\\ M\Omega.~\\ Typical~\\ specifications~\\ represent~\\ the~\\ most~\\ likely~\\ parametric~\\ norm.~\\ Min/Max~\\ Typical~\\ specifications~\\ represent~\\ the~\\ most~\\ likely~\\ parametric~\\ norm.~\\ Min/Max~\\ the~\\ the$ specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 6)		0.4		V/uS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	₫m			70		٥
Gain Margin	Gm			7.5		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 1.0 V		57		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to-Amplifier Isolation		(Note 7)		123		dB

^{6.} Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.

7. Input referred, $R_L = 100 \text{ k}\Omega$ connected to V+/2. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V, $\dot{V_O} = V+).$

5V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 5$ V, $V^- = 0$ V, $V_{CM} = V + /2$, $V_C = V^+ /2$ and $V_C = V_C =$

Parameter Symbo		Ondition Condition		Тур	Max	Unit	
Input Offset Voltage	V _{IO}	LMV931 (Single) (-40°C to +125°C)		1	6	mV	
		LMV932 (Dual) (-40°C to +125°C)		1	7.5		
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C	
Input Bias Current (Note 8)	Ι _Β	-40°C to +125°C		< 1		nA	
Input Offset Current (Note 8)	I _{IO}	-40°C to +125°C	-40°C to +125°C			nA	
Supply Current (per	I _{CC}	In Active Mode		95	210	μΑ	
Channel)		-40°C to +125°C			230		
Common-Mode	CMRR	$0~V \leq V_{CM} \leq 3.8~V, 4.6~V \leq V_{CM} \leq 5.0~V$	50	70		dB	
Rejection Ratio		-40°C to +125°C	50				
		$-0.2~V \leq V_{CM} \leq 0~V, 5.0~V \leq V_{CM} \leq 5.~2V$	50	70			
Power Supply	PSRR	$1.8 \text{ V} \leq \text{V}^{+} \leq 5 \text{ V}, \text{V}_{CM} = 0.5 \text{ V}$	50	70		dB	
Rejection Ratio		−40°C to +125°C	50				
Input Common-Mode Voltage Range	Vсм	For CMRR \geq 50 dB and T _A = 25 $^{\circ}$ C	V ⁻ - 0.2	-0.2 to 5.3	V ⁺ + 0.2	V	
		For CMRR \geq 50 dB and T _A = -40° C to $+85^{\circ}$ C	V -		V+	1	
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V- + 0.3		V+ - 0.3		
Large Signal Voltage	A _V	R_L = 600 Ω to 2.5 V, V_O = 0.2 V to 4.8 V	88	102		dB	
Gain LMV931 (Single) (Note 8)		-40° C to $+125^{\circ}$ C 87 $R_L = 2 \text{ k}\Omega$ to 2.5 V, $V_O = 0.2 \text{ V}$ to 4.8 V 94 113					
, , ,	-			113			
		-40°C to +125°C	93				
Large Signal Voltage	A _V	R_L = 600 Ω to 2.5 V, V_O = 0.2 V to 4.8 V	81	90			
Gain LMV932 (Dual) (Note 8)	_	−40°C to +125°C	78				
		R_L = 2 k Ω to 2.5 V, V_O = 0.2 V to 4.8 V	85	100		7	
		−40°C to +125°C	82				
Output Swing	V _{OH}	R_L = 600 Ω to 2.5 V, V_{IN} = ±100 mV	4.855	4.89		٧	
		−40°C to +125°C	4.835				
	V _{OL}	R_L = 600 Ω to 2.5 V, V_{IN} = ±100 mV		0.12	0.16		
		−40°C to +125°C			0.18		
	V _{OH}	R_L = 2 k Ω to 2.5 V, V_{IN} = \pm 100 mV	4.945	4.967			
		−40°C to +125°C	4.935				
	V _{OL}	R_L = 2 k Ω to 2.5 V, V_{IN} = ±100 mV		0.037	0.065		
		−40°C to +125°C			0.075		
Output Short-Circuit	I _O	Sourcing, Vo = 0 V, V_{IN} = +100 mV	55	65		mA	
Current		−40°C to +125°C	45				
		Sinking, Vo = 5 V, $V_{IN} = -100 \text{ mV}$	58	80			
		-40°C to +125°C	45				

^{8.} Guaranteed by design and/or characterization.

5V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_{+} = 5$ V, $V_{-} = 0$ V, $V_{CM} = 2.0$ V, $V_{0} = V_{+}/2$ and $R_{L} > 1$ M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 9)		0.48		V/uS
Gain Bandwidth Product	GBWP			1.5		MHz
Phase Margin	Θm			65		٥
Gain Margin	Gm			8		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 2 V		50		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to- Amplifier Isolation		(Note 10)		123		dB

Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.
 Input referred, R_L = 100 kΩ connected to V+/2. Each amp excited in turn with 1 kHz to produce V_O = 3 V_{PP}. (For Supply Voltages < 3 V, V_O = V+).

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$

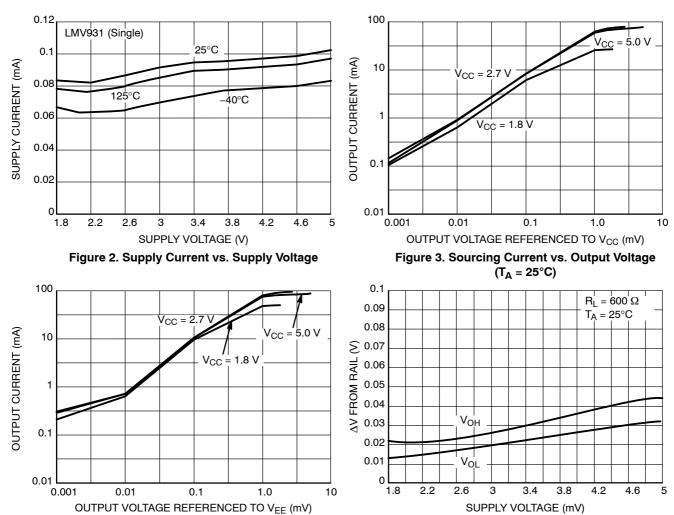


Figure 4. Sinking Current vs. Output Voltage $(T_A = 25^{\circ}C)$

Figure 5. Output Voltage Swing vs. Supply Voltage

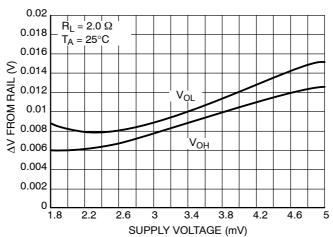


Figure 6. Output Voltage vs. Supply Voltage

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$

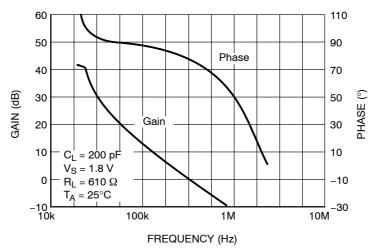


Figure 7. Gain and Phase vs. Frequency

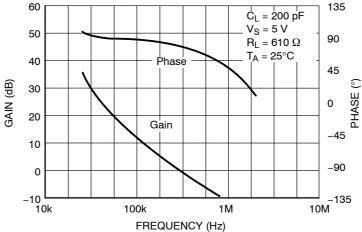


Figure 8. Gain and Phase vs. Frequency

TYPICAL CHARACTERISTICS

($T_A = 25^{\circ}C$ and $V_S = 5$ V unless otherwise specified)

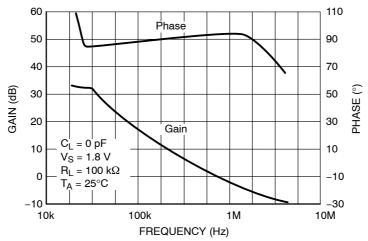


Figure 9. Gain and Phase vs. Frequency

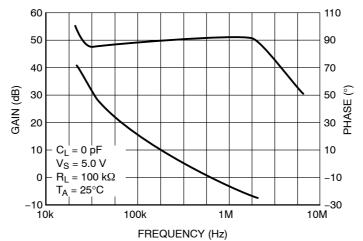


Figure 10. Gain and Phase vs. Frequency

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$

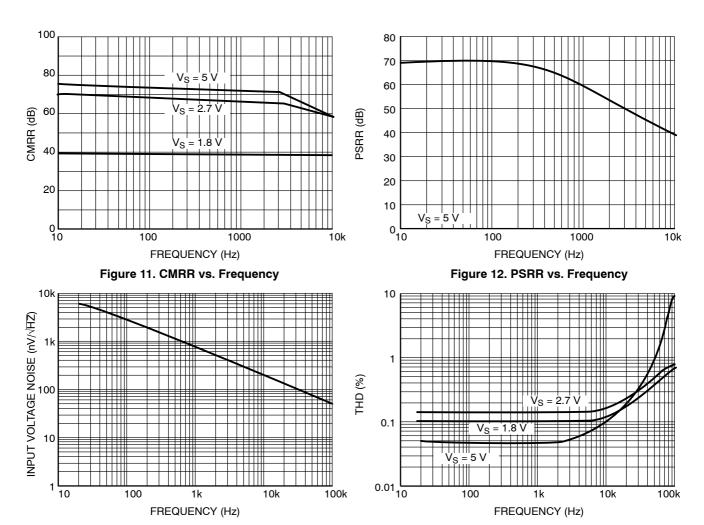


Figure 13. Input Voltage Noise vs. Frequency

Figure 14. THD vs. Frequency

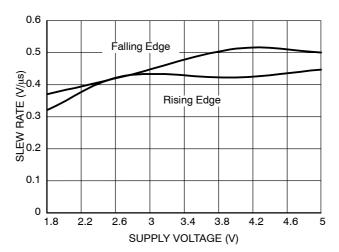


Figure 15. Slew Rate vs. Supply Voltage

TYPICAL CHARACTERISTICS

($T_A = 25^{\circ}C$ and $V_S = 5~V$ unless otherwise specified)



TIME (2µs/div)

Figure 16. Small Signal Noninverting Response



TIME (2µs/div)

Figure 17. Small Signal Noninverting Response

TYPICAL CHARACTERISTICS

($T_A = 25^{\circ}C$ and $V_S = 5~V$ unless otherwise specified)



TIME (2µs/div)

Figure 18. Small Signal Noninverting Response



TIME (2µs/div)

Figure 19. Large Signal Noninverting Response

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$



TIME (2µs/div)

Figure 20. Large Signal Noninverting Response

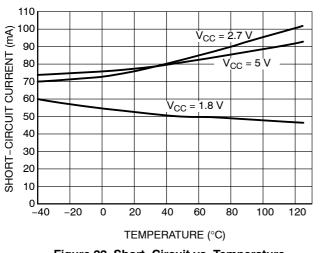


TIME (2µs/div)

Figure 21. Large Signal Noninverting Response

TYPICAL CHARACTERISTICS

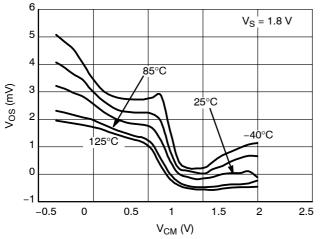
 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$



110 100 SHORT-CIRCUIT CURRENT (mA) 90 $V_{CC} = 5 V$ 80 70 60 $V_{CC} = 2.7 \text{ V}$ 50 40 30 20 V_{CC} = 1.8 V 10 -20 -40 60 100 120 TEMPERATURE (°C)

Figure 22. Short-Circuit vs. Temperature (Sinking)

Figure 23. Short-Circuit vs. Temperature (Sourcing)



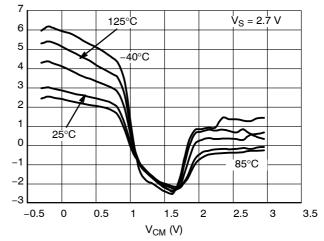
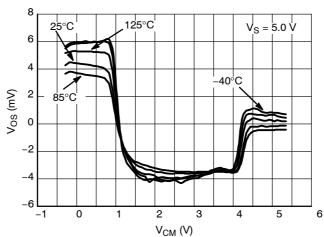


Figure 24. Offset Voltage vs. Common Mode Range V_{DD} 1.8 V

Figure 25. Offset Voltage vs. Common Mode Range V_{DD} 2.7 V



Vos (mV)

Figure 26. Offset Voltage vs. Common Mode Range V_{DD} 5.0 V

APPLICATION INFORMATION

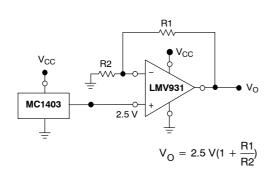


Figure 27. Voltage Reference

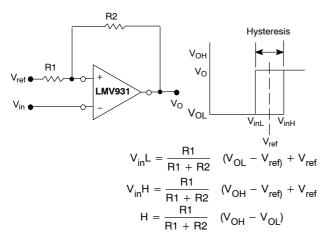


Figure 29. Comparator with Hysteresis

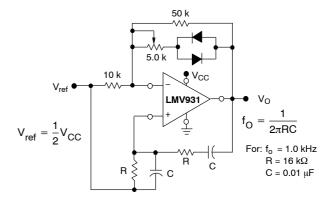
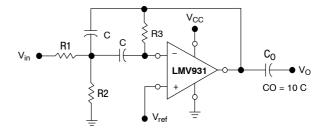


Figure 28. Wien Bridge Oscillator



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value f_0 , $\frac{C}{Q}$ Then: $R3 = \frac{Q}{\pi f_0 C}$ $R1 = \frac{R3}{2 A(f_0)}$ $R2 = \frac{R1 R3}{40^2 R1 R3}$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_O and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 30. Multiple Feedback Bandpass Filter

ORDERING INFORMATION

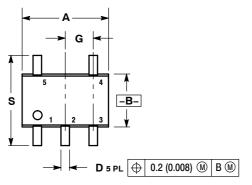
Order Number	Number of Channels	Number of Pins	Package Type	Shipping [†]
LMV931SQ3T2G	Single	5	SC70-5 (Pb-Free)	3000 / Tape & Reel
LMV931SN3T1G	Single	5	TSOP-5 (Pb-Free)	3000 / Tape & Reel
LMV932DMR2G*	Dual	8	Micro8 (Pb-Free)	4000 / Tape & Reel

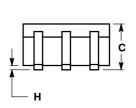
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

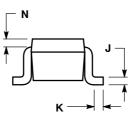
^{*}Consult Sales.

PACKAGE DIMENSIONS

SC-88A, SOT-353, SC-70 CASE 419A-02 **ISSUE J**





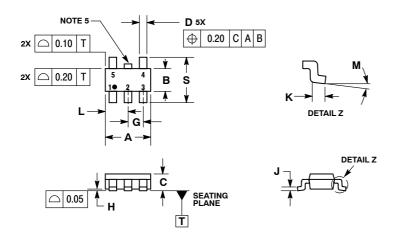


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008	REF	0.20 REF		
S	0.079	0.087	2.00	2.20	

PACKAGE DIMENSIONS

TSOP-5 CASE 483-02 **ISSUE H**



NOTES:

- NOTES:

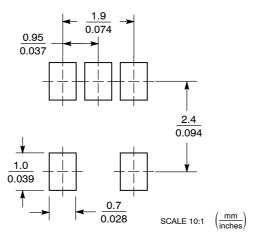
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS. 3 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIA
- OF BASE MATERIAL.

 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE
- MOLD FLOATH, FRO TROSIONS, OR GATE BURRS. 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIN	IETERS
DIM	MIN	MAX
Α	3.00	BSC
В	1.50	BSC
С	0.90	1.10
D	0.25	0.50
G	0.95	BSC
Н	0.01	0.10
J	0.10	0.26
K	0.20	0.60
L	1.25	1.55
М	0 °	10 °
۰.	2.50	3 00

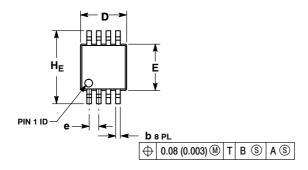
SOLDERING FOOTPRINT*

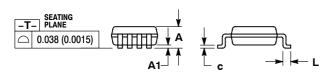


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8™ CASE 846A-02 **ISSUE H**

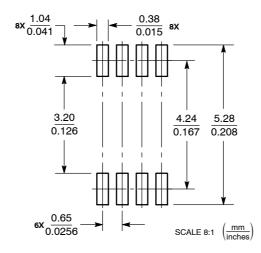




- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	М	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α			1.10			0.043		
A1	0.05	0.08	0.15	0.002	0.003	0.006		
b	0.25	0.33	0.40	0.010	0.013	0.016		
С	0.13	0.18	0.23	0.005	0.007	0.009		
D	2.90	3.00	3.10	0.114	0.118	0.122		
E	2.90	3.00	3.10	0.114	0.118	0.122		
е		0.65 BSC		0.026 BSC				
L	0.40	0.55	0.70	0.016	0.021	0.028		
HE	4.75	4.90	5.05	0.187	0.193	0.199		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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